Unit: mm



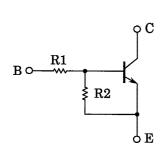
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1501,RN1502,RN1503 RN1504,RN1505,RN1506

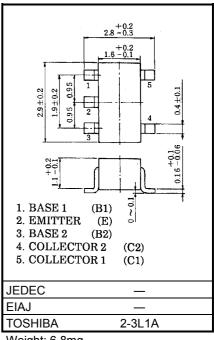
Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Including two devices in SMV (super mini type with 5 leads) With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2501~RN2506

Equivalent Circuit and Bias Resister Values



Type No.	R1 (kΩ) R2 (kg	
RN1501	4.7	4.7
RN1502	10	10
RN1503	22	22
RN1504	47	47
RN1505	2.2	47
RN1506	4.7	47



Weight: 6.8mg

Equivalent Circuit (Top View)

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characterist	Symbol	Rating	Unit		
Collector-base voltage	RN1501~1506	V_{CBO}	50	٧	
Collector-emitter voltage	KN1301*1300	V _{CEO}	50	٧	
Emitter-base voltage	RN1501~1504	V _{EBO}	10	V	
	RN1505, 1506	vEBO	5		
Collector current		I _C	100	mA	
Collector power dissipation	RN1501~1506	Pc*	300	mW	
Junction temperature	KN 150 1~ 1506	Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

^{*} Total rating

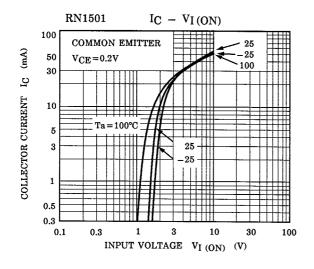


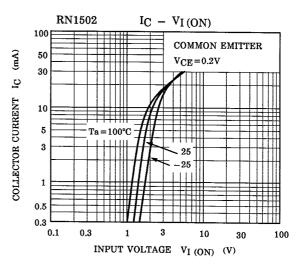
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

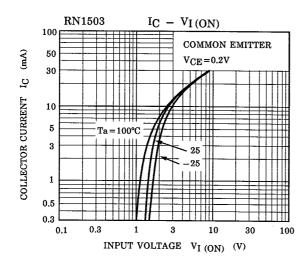
Characteri	stic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1501~1506	I _{CBO}		$V_{CB} = 50V, I_{E} = 0$	_	_	100	nΛ
	KN 150 1~ 1500	I _{CEO}		V _{CE} = 50V, I _B = 0	_	_	500	nA
	RN1501			V _{EB} = 10V, I _C = 0	0.82	_	1.52	mA
Emitter cut-off current	RN1502	I _{EBO}	_		0.38	_	0.71	
	RN1503				0.17	_	0.33	
	RN1504				0.082	_	0.15	
	RN1505				0.078	_	0.145	
	RN1506			$V_{EB} = 5V, I_C = 0$	0.074	_	0.138	
	RN1501				30	_	_	
	RN1502				50	_	_	
DO summed main	RN1503	L.)/ 5)/ 40m	70	_	_	
DC current gain	RN1504	h _{FE}	_	V _{CE} = 5V, I _C = 10mA	80	_	_	
	RN1505				80	_	_	
	RN1506				80	_	_	
Collector-emitter saturation voltage	RN1501~1506	V _{CE (sat)}	_	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	V
	RN1501	V _{I (ON)} —		V _{CE} = 0.2V, I _C = 5mA	1.1	_	2.0	V
	RN1502				1.2	_	2.4	
	RN1503				1.3	_	3.0	
Input voltage (ON)	RN1504		_		1.5	_	5.0	
	RN1505				0.6	_	1.1	
	RN1506				0.7	_	1.3	
(055)	RN1501~1504	V _{I (OFF)} —		V _{CE} = 5V, I _C = 0.1mA	1.0	_	1.5	٧
Input voltage (OFF)	RN1505, 1506		_		0.5	_	0.8	
Transition frequency	RN1501~1506	f _T	_	V _{CE} = 10V, I _C = 5mA	_	250	_	MHz
Collector Output capacitance	RN1501~1506	C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1MHz	_	3	6	pF
Input resistor	RN1501				3.29	4.7	6.11	kΩ
	RN1502	R1 —		_	7	10	13	
	RN1503				15.4	22	28.6	
	RN1504		_		32.9	47	61.1	
	RN1505			1.54	2.2	2.86		
	RN1506				3.29	4.7	6.11	
Resistor ratio	RN1501~1504		_		0.9	1.0	1.1	
	RN1505	R1/R2			0.0421	0.0468	0.0515	
	RN1506				0.09	0.1	0.11	

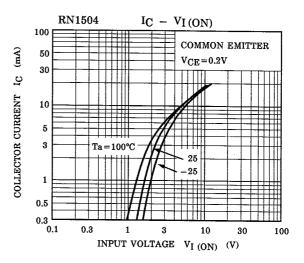
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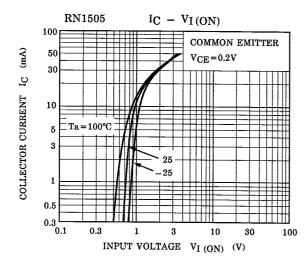
(Q1, Q2 COMMON)

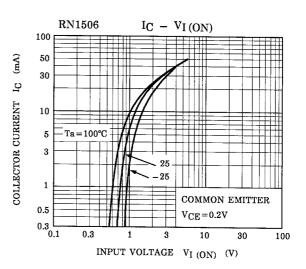






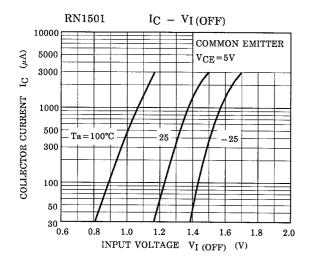


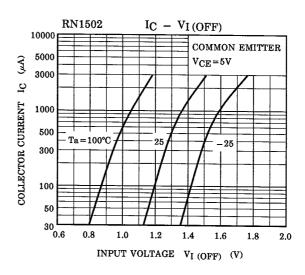


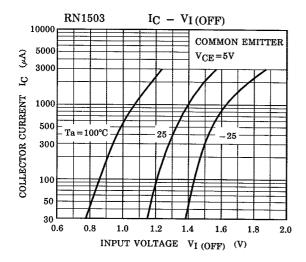


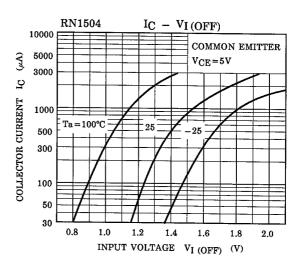
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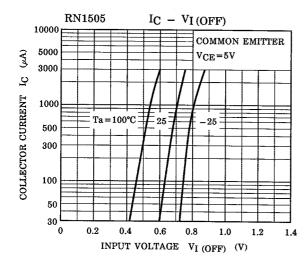
(Q1, Q2 COMMON)

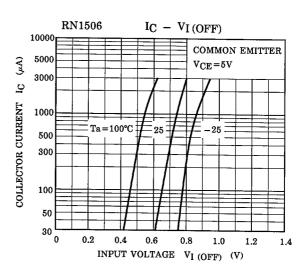




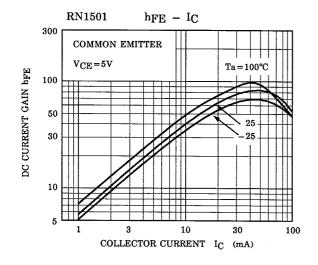


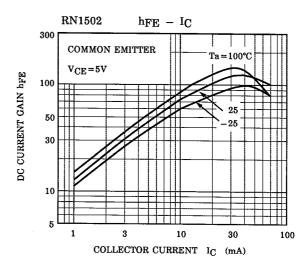


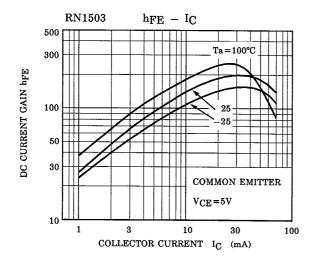


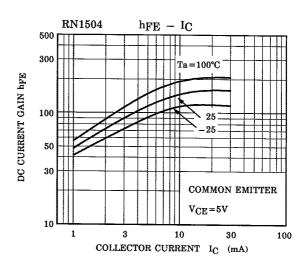


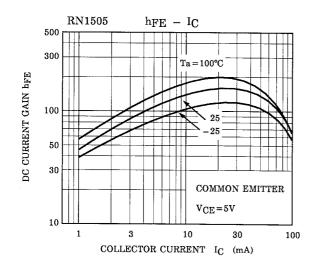
(Q1, Q2 COMMON)

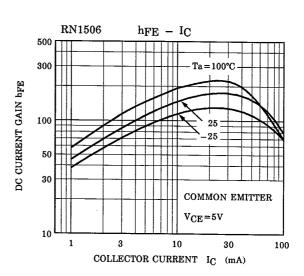












5

Type Name	Marking
RN1501	Type Name X A
RN1502	Type Name X B
RN1503	Type Name XC
RN1504	Type Name X D
RN1505	Type Name X E
RN1506	Type Name X F HHH

6 2001-06-07

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